

40V PNP MEDIUM POWER TRANSISTOR IN SOT223

Features

- BV_{CEO} > -40V
- I_C = -1A High Continuous Current
- Low Saturation Voltage V_{CE(SAT)} < -500mV @ -1A
- Complementary NPN Type: FZT491A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.112 grams (Approximate)

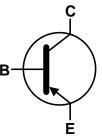
Applications

- Power MOSFET & IGBT Gate Driving
- Low Loss Power Switching

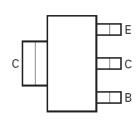
SOT223 (Type DN)







Device Symbol



Top View Pin-Out

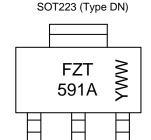
Ordering Information (Notes 4 & 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT591ATA	AEC-Q101	FZT591A	7	12	1,000
FZT591AQTA	Automotive	FZT591A	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



FZT 591A = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 9 = 2019) WW or $\overline{W}W$ = Week Code (01 to 53)



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	Ic	-1	Α
Base Current	Ι _Β	-200	mA
Peak Pulse Current	I _{CM}	-2	Α

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	D	2	W
Power Dissipation	(Note 7)	P _D	3	W
Thermal Resistance, Junction to Ambient	(Note 6)	D	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 7)	R _{0JA}	41.7	°C/W
Thermal Resistance, Junction to Leads (Note 8	$R_{ heta JL}$	19.4	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	٧	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 6. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

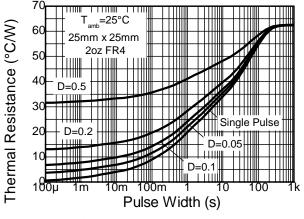
 7. Same as Note 6, except mounted on 50mm x 50mm 2oz copper.

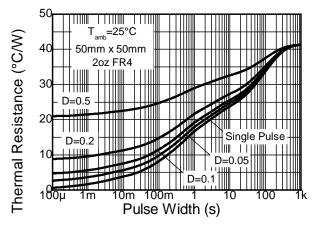
 8. Thermal resistance from junction to solder-point (at the end of the collector lead).

 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



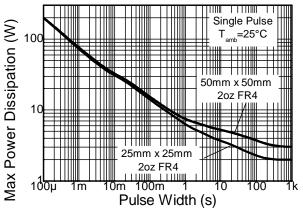
Thermal Characteristics and Derating Information

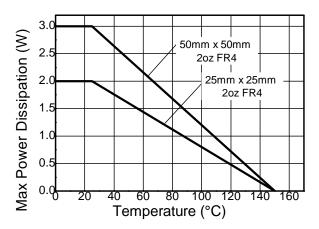




Transient Thermal Impedance

Transient Thermal Impedance





Pulse Power Dissipation

Derating Curve



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-40	-	_	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-40	-	_	V	$I_C = -10 \text{mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-	_	V	$I_E = -100 \mu A$
Collector Cut-Off Current	I _{CBO}	-	-	-100	nA	V _{CB} = -30V
Collector Cut-Off Current	I _{CES}	-	_	-100	nA	V _{CES} = -30V
Emitter Cut-Off Current	I _{EBO}	-	-	-100	nA	$V_{EB} = -4V$
Collector-Emitter Saturation Voltage (Note 10)	V _{CE(SAT)}		_ _	-0.2 -0.35 -0.5	V	$I_C = -100\text{mA}, I_B = -1\text{mA}$ $I_C = -500\text{mA}, I_B = -20\text{mA}$ $I_C = -1\text{A}, I_B = -100\text{mA}$
Base-Emitter Saturation Voltage (Note 10)	V _{BE(SAT)}	-	-	-1.1	V	$I_C = -1A$, $I_B = -50mA$
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(ON)}	-	-	-1.0	V	$I_{C} = -1A$, $V_{CE} = -5V$
DC Current Transfer Static Ratio (Note 10)	hFE	300 300 250 160 30	- - - -	- 800 - - -	_	$I_C = -1mA$, $V_{CE} = -5V$ $I_C = -100mA$, $V_{CE} = -5V$ $I_C = -500mA$, $V_{CE} = -5V$ $I_C = -1A$, $V_{CE} = -5V$ $I_C = -2A$, $V_{CE} = -5V$
Transitional Frequency (Note 10)	f⊤	150	_	-	MHz	$V_{CE} = -10V, I_{C} = -50mA$ f = 100MHz
Output Capacitance (Note 10)	C _{obo}	-	-	10	pF	V _{CB} = -10V, f = 1MHz

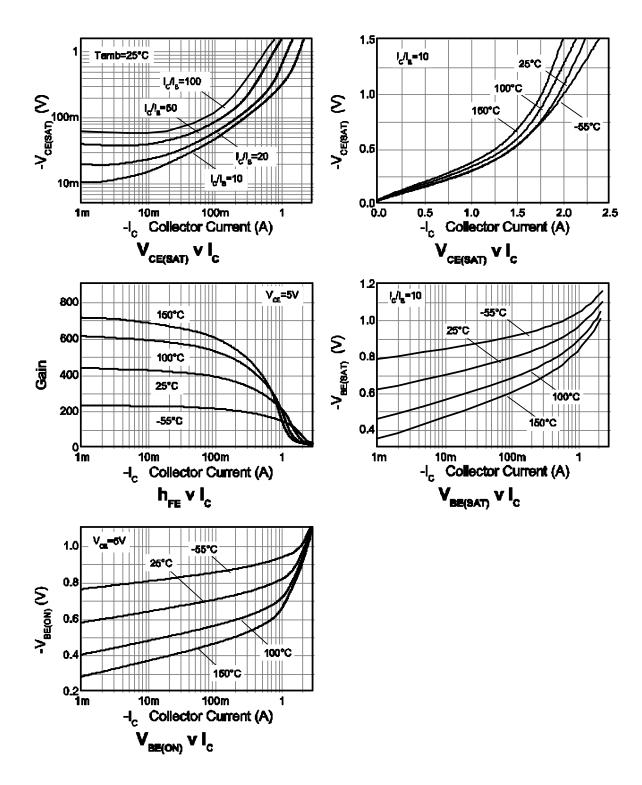
Note: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

July 2019

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Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

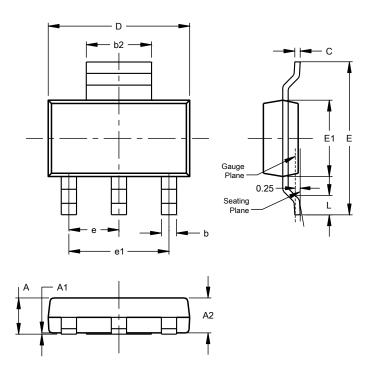




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

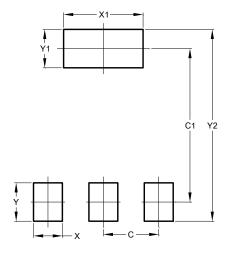


SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
С	0.20	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
е			2.30		
e1			4.60		
L	0.85				
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
V2	8.00



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